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PHOTO DIODE NR8300FP-CC

$_{\phi30}~\mu m$ InGaAs APD IN COAXIAL PACKAGE FOR FIBER OPTIC COMMUNICATION AND OTDR APPLICATIONS

FEATURES

- SMALL DARK CURRENT: ID = 5 nA
- SMALL TERMINAL CAPACITANCE: CT = 0.35 pF at 0.9 VBR
- HIGH QUANTUM EFFICIENCY: $\eta = 90\%$ at $\lambda = 1310$ nm, M = 1 $\eta = 77\%$ at $\lambda = 1550$ nm, M = 1
- HIGH SPEED RESPONSE: fc = 2.5 GHz at M = 10
- **DETECTING AREA SIZE:** φ30 μm
- COAXIAL MODULE WITH SINGLE MODE FIBER (SM-9/125)

DESCRIPTION

The NR8300FP-CC is an InGaAs avalanche photo diode module with single mode fiber. It is designed for optical test instruments, especially OTDR systems.

ELECTRO-OPTICAL CHARACTERISTICS (Tc = 25°C, unless otherwise specified)

	PART NUMBER			NR8300FP-CC	
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	ТҮР	MAX
VBR	Reverse Breakdown Voltage, ID = 100 μA	V	50	70	100
δ	Temperature Coefficient of Reverse Breakdown Voltage ¹	%/°C		0.2	
lD	Dark Current, VR = VBR x 0.9	nA		5	25
ldм	Multiplied Dark Current, M = 2 to 10	nA		1	5
Ct	Terminal Capacitance, VR = VBR x 0.9, f = 1 MHz	pF		0.35	0.60
fc	Cut-off Frequency, M = 10	GHz	2.5		
η	Quantum Efficiency, λ = 1310 nm, M = 1 λ = 1550 nm, M = 1	%	76 65	90 77	
S	Responsivity, λ = 1310 nm, M = 1 λ = 1550 nm, M = 1	A/W	0.80 0.81	0.94 0.96	
М	Multiplication Factor, λ = 1310 nm, IPO = 1.0 μ A, VR = V (at ID = 1 μ A)	М	30	40	
X F	Excess Noise Factor ² , λ = 1310 nm, 1 550 nm, IPO = 1.0 μ A, M = 10, f = 35 MHz, B = 1 MHz	_		0.7 5	
ORL	Optical Return Loss, SMF	dB	30		

 $VBR < 25^{\circ}C + \Delta T^{\circ}C > - VBR < 25^{\circ}C >$

Note: $1.\delta = --$

 $\Delta T^{\circ}C > - V_{BR} < 25^{\circ}C >$

2. $F = M^{X}$

ABSOLUTE MAXIMUM RATINGS¹

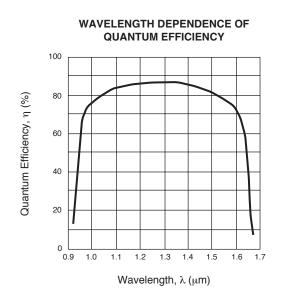
(Tc = 25°C, unless otherwise specified)

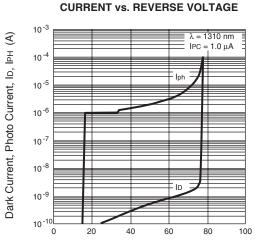
SYMBOLS	PARAMETERS	UNITS	RATINGS
lF	Forward Current	mA	10
IR	Reverse Current	mA	0.5
Тс	Operating Case Temp.	°C	-40 to +85
Tstg	Storage Temperature	°C	-40 to +85
TSOL	Lead Soldering Temp.	°C	260 (10 sec.)
RH	Relative Humidity (noncondensing)	%	85

Note:

1. Operation in excess of any one of these parameters may result in permanent damage.

TYPICAL PERFORMANCE CURVES (Tc = 25°C, unless otherwise specified)

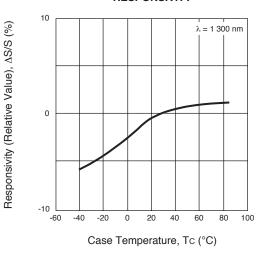




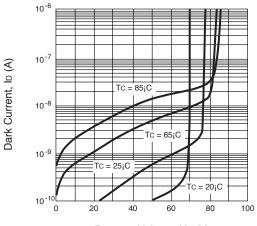
DARK CURRENT AND PHOTO

Reverse Voltage, VR (V)

TEMPERATURE DEPENDENCE OF RESPONSIVITY

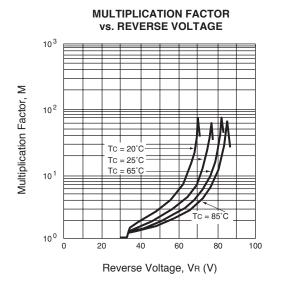


DARK CURRENT vs. REVERSE VOLTAGE

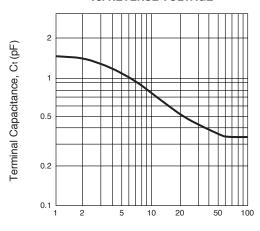


Reverse Voltage, VR (V)

TYPICAL PERFORMANCE CURVES (Tc = 25°C)

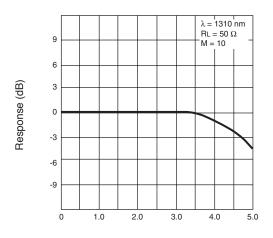


TERMINAL CAPACITANCE vs. REVERSE VOLTAGE



Reverse Voltage, VR (V)

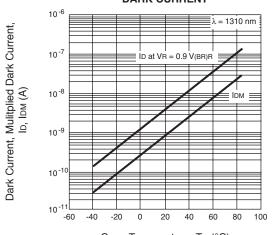
FREQUENCY RESPONSE



Frequency, f (GHz)

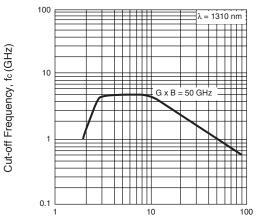
Remark: The graphs indicate nominal characteristics.

TEMPERATURE DEPENDENCE OF DARK CURRENT vs. MULTIPLIED DARK CURRENT



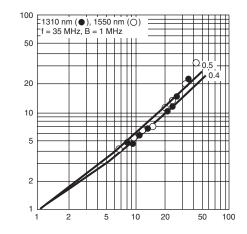
Case Temperature, Tc (°C)

CUT-OFF FREQUENCY vs. MULTIPLICATION FACTOR



Multiplication Factor, M

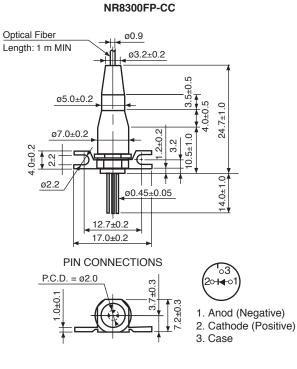
EXCESS NOISE FACTOR vs. MULTIPLICATION FACTOR



Excess Noise Factor, F

Multiplication Factor, M

OUTLINE DIMENSIONS (Units in mm)



ORDERING INFORMATION

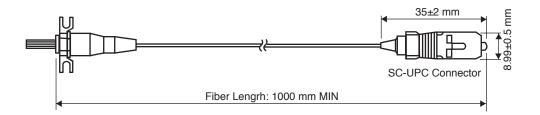
	Part Number	Flange Type	Fiber Type	Available Connector
Ν	NR8300FP-CC-AZ*	Flat Mount Flange	SMF	With SC-UPC Connector

*NOTE:

Please refer to the last page of this data sheet, "Compliance with EU Directives" for Pb-Free RoHS Compliance Infomation.

OPTICAL FIBER CHARACTERISTICS

PARAMETER	SPECIFICATION	UNIT	
Mode Field Diameter	9.5±1	μm	
Core Diameter	-	μm	
Cladding Diameter	125±2	μm	
Maximum Cladding Noncircularity	2	%	
Maximum Core/Cladding Concentricity	1.6	%	
Outer Diameter	0.9±0.1	mm	
Cut-off Wavelength	1100 to 1270	nm	
Minimum Fiber Bending Radius	30	mm	
Fiber Length	1000 Min.	mm	
Flammability	UL1581 VW-1		



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